



BV <sub>DSX</sub> / BV <sub>DGX</sub>	R <sub>DS(on)</sub> (max)	I <sub>DSS</sub> (min)	Package
800V	45Ω	100mA	SOT-223

#### **Features**

High Breakdown Voltage: 800V

Low On-Resistance: 45Ω max. at 25°C

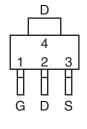
Low V<sub>GS(off)</sub> Voltage: -1.4 to -3.1V
High Input Impedance

Small Package Size: SOT-223

## **Applications**

- Normally-On Switches
- Solid State Relays
- Converters
- Telecommunications
- Power Supply
- Current Regulators

## **Package Pinout**



#### **Description**

The CPC3980 is an 800V, N-channel, depletion-mode, Field Effect Transistor (FET) created using IXYS Integrated Circuits Division's proprietary vertical DMOS process. Yielding a robust device with high input impedance, this process enables world class, high voltage MOSFET performance with an economical silicon gate architecture.

As with all MOS devices, the FET structure prevents thermal runaway and thermal-induced secondary breakdown, which makes the CPC3980 ideal for use in high-power applications.

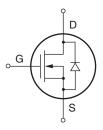
The CPC3980 is a highly reliable FET device that has been used extensively in IXYS Integrated Circuits Division's Solid State Relays for industrial and telecommunications applications.

The CPC3980 is available in the SOT-223 package.

## **Ordering Information**

Part #	Description
CPC3980ZTR	SOT-223: Tape and Reel (1000/Reel)

# **Circuit Symbol**











# Absolute Maximum Ratings @ 25°C

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Parameter	Ratings	Units
Drain-to-Source Voltage	800	V
Gate-to-Source Voltage	±15	V
Pulsed Drain Current	150	mA
Total Package Dissipation <sup>1</sup>	1.8	W
Operational Temperature	-55 to +125	°C
Junction Temperature, Maximum	+125	°C
Storage Temperature	-55 to +125	°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

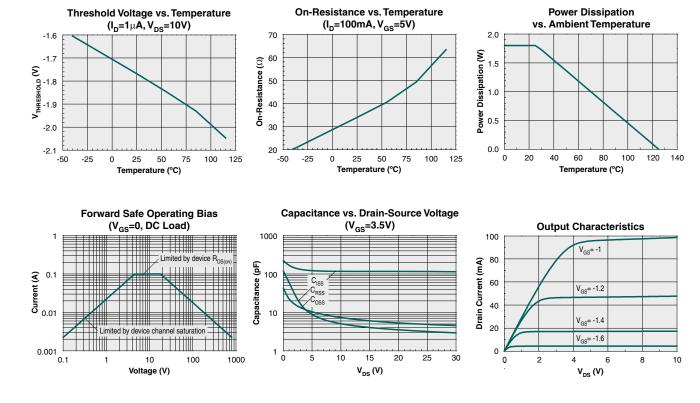
# **Electrical Characteristics @ 25°C (Unless Otherwise Noted)**

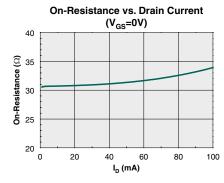
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Drain-to-Source Breakdown Voltage	BV <sub>DSX</sub>	$V_{GS} = -5.5V, I_{D} = 100\mu A$	800	-	-	V
Gate-to-Source Off Voltage	V <sub>GS(off)</sub>	$V_{DS} = 15V, I_{D} = 1\mu A$	-1.4	-	-3.1	V
Change in V <sub>GS(off)</sub> with Temperature	dV <sub>GS(off)</sub> /dT	V <sub>DS</sub> = 15V, I <sub>D</sub> =1μA	-	-	4.5	mV/°C
Gate Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 15V, V_{DS}=0V$	-	-	100	nA
Drain-to-Source Leakage Current	I <sub>D(off)</sub>	$V_{GS} = -5.5V, V_{DS} = 800V$	-	-	1	μΑ
Saturated Drain-to-Source Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> =15V	100	-	-	mA
Static Drain-to-Source On-State Resistance	R <sub>DS(on)</sub>	\\ 0\\   100m\ \\ 10\\	-	-	45	Ω
Change in R <sub>DS(on)</sub> with Temperature	dR <sub>DS(on)</sub> /dT	$V_{GS} = 0V, I_{D} = 100 \text{mA}, V_{DS} = 10V$	-	-	2.5	%/°C
Forward Transconductance	G <sub>fs</sub>	$I_{D} = 50 \text{mA}, V_{DS} = 10 \text{V}$	100	-	-	m℧
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> = -3.5V		115		
Common Source Output Capacitance	C <sub>OSS</sub>	$V_{DS} = 25V$	-	5	-	pF
Reverse Transfer Capacitance	C <sub>RSS</sub>	f= 1MHz		3		
Source-Drain Diode Voltage Drop	V <sub>SD</sub>	$V_{GS} = -5V, I_{SD} = 150 \text{mA}$	-	0.72	1	V
Thermal Resistance						
Junction to Ambient	$\Theta_{JA}$	-	-	55	-	00/14/
Junction to Case	$\Theta_{JC}$	-	-	23	-	°C/W

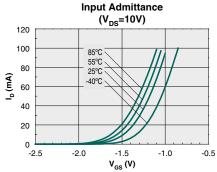
<sup>&</sup>lt;sup>1</sup> Mounted on 1"x1" 2 oz. Copper FR4 board.

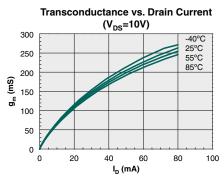


# PERFORMANCE DATA @25°C (Unless Otherwise Noted)\*









<sup>\*</sup>The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.



## **Manufacturing Information**

#### **Moisture Sensitivity**

All plastic encapsulated semiconductor packages are susceptible to moisture ingression. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, IPC/JEDEC J-STD-020, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
CPC3980Z	MSL 1

#### **ESD Sensitivity**



This product is ESD Sensitive, and should be handled according to the industry standard JESD-625.

#### **Reflow Profile**

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
CPC3980Z	260°C for 30 seconds

#### **Board Wash**

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable, and the use of a short drying bake may be necessary. Chlorine-based or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.



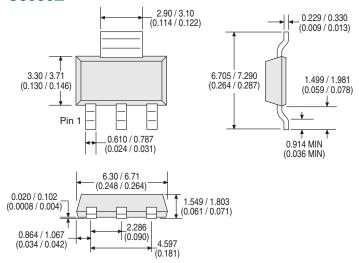




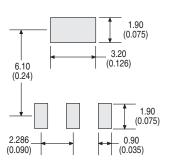


### **Mechanical Dimensions**

#### **CPC3980Z**

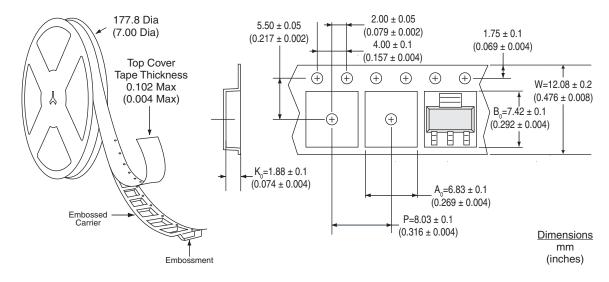


#### **PCB Land Pattern**



<u>Dimensions</u> mm MIN / mm MAX (inches MIN / inches MAX)

## CPC3980ZTR Tape & Reel



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